

Applications

- 5 GHz WLAN (IEEE802.11a/g/n)
- Access Points, PCMCIA, PC cards, Handhelds

Features

- 5GHz Front End Module with PA, LNA and T/R Switch
- Integrated power amplifier enable pin (VEN)
- Buffered, temperature compensated power detector
- High and Low-Linearity mode
- 3% EVM, @17dBm, 64 QAM, 54 Mbps
- 30 dB Typical Gain
- Lead Free and RoHS compliant, halogen free package
- 16 pin 3 mm x 3 mm x 0.6 mm QFN, MSL1

Ordering Information

Part Number	Package	Remark
SE5007BT	16 Pin QFN	Samples
SE5007BT-R	16 Pin QFN	Tape and Reel
SE5007BT- EK1	Evaluation Kit	Standard

Product Description

The SE5007BT is a 5GHz front end module offering high linear power for wireless LAN applications. It incorporates a power detector for control of the output power.

The SE5007BT offers a high level of integration for a simplified design, providing quicker time to market and higher application board production yield. The device integrates inter-stage match, a temperature compensated, load insensitive power detector with 20dB of dynamic range, a 3.8GHz notch filter, a T/R switch and an Rx LNA.

For wireless LAN applications, the device meets the requirements of IEEE802.11a and delivers approximately 17dBm of linear output power. It also features a low linearity mode control to reduce current consumption at low power modes.

The SE5007BT integrates the reference voltage generator, allowing for a true 1.8V CMOS compatible digital EN (enable) function to turn the power amplifier on and off.

Functional Block Diagram

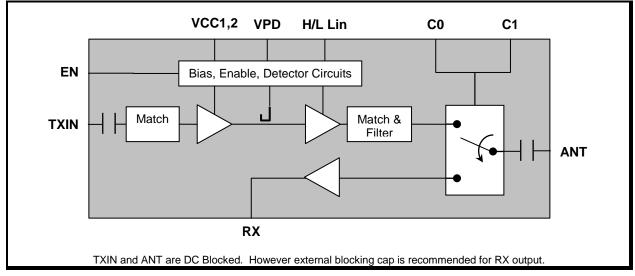


Figure 1: Functional Block Diagram



Pin Out Diagram

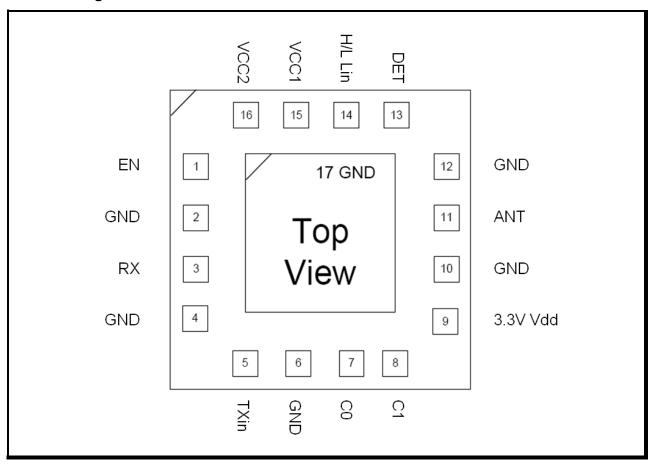


Figure 2: SE5007BT Pin-Out Diagram

Pin Out Description

Pin No.	Name	Description	Pin No.	Name	Description
1	EN	PA Enable	9	VDD	LNA Supply Voltage (3.3V+/-10% only)
2	GND	Ground	10	GND	Ground
3	RX	5GHz LNA Output Signal	11	ANT	5GHz Antenna output
4	GND	Ground	12	GND	Ground
5	TXIN	5GHz TX RF Input Signal	13	DET	Power Detector Output
6	GND	Ground	14	H/L Lin	High-Low linearity Control
7	C0	Switch Control Logic 1	15	VCC1	Power Stage Supply Voltage
8	C1	Switch Control Logic 2	16	VCC2	Bias, Driver Stage Supply Voltage



Absolute Maximum Ratings

These are stress ratings only. Exposure to stresses beyond these maximum ratings for a long period of time may cause permanent damage to, or affect the reliability of the device. Avoid operating the device outside the recommended operating conditions defined below. This device is ESD sensitive. Handling and assembly of this device should be at ESD protected workstations.

Symbol	Defir	Min.	Max.	Unit	
Vcc1	Supply Voltage on pin 15	-0.3	4.8	V	
Vdd, Vcc2	Supply Voltage on pins 9,	-0.3	3.6	V	
EN	DC input on Enable	-0.3	3.6	V	
TXIN	RF Input Power, RFout int	o 50Ω match	-	12	dBm
Тѕтс	Storage Temperature Ran	ge	-40	150	°C
ESD	JEDEC JESD22-A114	Antenna Pin	-	1000	V
ESD _{HBM}	all pins All Other Pins		-	350	v

Recommended Operating Conditions

Symbol	Parameter	Min.	Max.	Unit
Vcc1	Supply Voltage on pin 15 (VCC1)	3.0	4.5	V
VDD, VCC2	Supply Voltage on pins 9, 16 (VDD, VCC2)	3.0	3.6	V
TA	Ambient Temperature	-40	85	°C

Control Logic Characteristics

Conditions: V_{CC1} = V_{CC2} = V_{DD} = V_{PAON} = V_{EN} = 3.3 V, T_A = 25 °C, as measured on Skyworks Solutions' SE5007T-EV1 evaluation board, unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
ICC-802.11a		P_{OUT} = 17 dBm, 54 Mbps, 64 QAM, H/L Lin = 3.3V (High Linearity Mode)	-	195	-	
	Supply Current,	P _{OUT} = 13 dBm, 54 Mbps, 64 QAM, H/L Lin = 0V (Low Linearity Mode)	-	140	-	
	Transmit Mode Supply Current,	P _{OUT} = 5 dBm, 54 Mbps, 64 QAM, H/L Lin = 0V (Low Linearity Mode)	-	105	-	mA
		P _{OUT} = 19 dBm, 54 Mbps, 64 QAM, H/L Lin = 3.3V, VCC1 = 4.0V		220		
		$V_{EN} = C0 = 0V; C1 = 3.3V$		15		
	Receive Mode	$V_{EN} = C0 = C1 = 0V$		0.02		
IOFF	Supply Current	$V_{EN} = 0 V$, No RF, C0=C1=0 V Measured on VCC, VDD pins	-	20	50	μA
Venh	Logic High Voltage	-	1.6	-	Vcc	V



Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Venl	Logic Low Voltage	-	-0.3	-	0.3	V
Ienh	Input Current Logic High Voltage	-	-	330	400	μA
Ienl	Input Current Logic Low Voltage	-	-	<1	-	μA

Switch Logic Characteristics

Conditions: Vcc = Vbb VEN = 3.3 V, TA = 25 °C, as measured on Skyworks Solutions' SE5007BT-EK1 evaluation board, all unused ports terminated with 50 ohms, unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
ON	Low Loss Switch Control Voltage	High State = Vctl_on - Vctl_off	2.8	-	3.6	V
OFF	High Loss Switch Control Voltage	Low State = Vctl_OFF - Vctl_OFF	0	-	0.3	V
Сст∟	Control Input Capacitance	-	-	-	100	pF
ICTL	Control Line Current	Vctl = Vctl_on	-	2	10	uA

Switch Control Logic Table

C0	C1	EN	Hi/L Lin	ANT		
ON	OFF	ON	OFF	TX Low Linearity		
ON	OFF	ON	ON	TX High Linearity		
OFF	OFF	OFF	D/C	Rx Bypass		
OFF	ON	OFF	D/C	Rx LNA ON		
ON	ON	Un-supported state				



AC Electrical Characteristics

Transmit Characteristics

Conditions:	Vcc1 = Vcc2 = Vdd = VEN = C0 = H/L Lin = 3.3V, C1 = 0V, TA = 25 °C, as measured on Skyworks
	Solutions' SE5007T-EV1 evaluation board, unless otherwise noted

Symbol	Parameter	Condit		Min.	Тур.	Max.	Unit
f∟-∪	Frequency Range	-		4.90	-	5.85	GHz
		802.11a,	EVM = 3%	-	17	-	
	Output Power,	64 QAM	EVM = 2%	-	15	-	
	High Linearity Mode H/L Lin = 3.3V OFDM POUT	VCC1 = 4.0V, 3% EVM	EVM = 3%	-	19	-	
POUT		MCS0, HT20, ma	sk compliant	-	21	-	dBm
		MCS0, HT40, ma	sk compliant	-	20	-	
	Output Power,	802.11a, 64 QAN	l, EVM = 3%	-	13	-	
	Low Linearity Mode H/L Lin = 0V	MCS0, HT20, ma	sk compliant	-	17	-	
	OFDM	MCS0, HT40, ma	sk compliant	-	16	-	
P _{1dB}	Output 1dB compression point	No modulation		-	24	-	dBm
S 11	Input Return Loss	PIN = -25 dBm		-	14	-	dB
S 21	Small Signal Gain,	High Linearity Mo	de	28	31	-	dB
321	$P_{IN} = -25 dBm$	Low Linearity Mo	de	26	30	-	
ΔS 21	Small Signal Gain	Gain variation ove 40MHz channel	er single	-	-	0.5	dB
<u> </u>	Variation	Gain Variation ov	er band	-1.5	-	1.5	u D
S21_3.8	Out of Band Gain	Gain at 3.8GHz		-	-	15	dB
2f	Harmonic	Роит = 17 dBm, C		-	-50	-42	dBm/MHz
Зf				-	-50	-42	UDITI/IVITIZ
tr, tf	Rise and Fall Time	-		-	0.5	-	us
STAB	Stability	Pout = 17 dBm, 5 QAM, VSWR = 6	All non-ł		ly related o dBc/100 kl	outputs less Hz	
Rugged- ness	Tolerance to output load mismatching	Constant P _{IN} equa dBm at 50ohms, QAM, VSWR = 6	54 Mbps, 64	No damage			
Robust	Robustness to input power	P _{IN} = 12dBm, CW all phases	/, VSWR = 6:1,		No c	lamage	



Receive Characteristics

Conditions: Vcc = C1 = V_{DD=} 3.3V, V_{EN} = C0 = 0V, T_A = 25 °C, as measured on Skyworks Solutions' SE5007BT-EK1 evaluation board, all unused ports terminated with 50 ohms, unless otherwise noted.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit	
Fout	Frequency Range	-	4.9	-	5.85	GHz	
RX	Insertion Loss	Bypass Mode: C0 = C1 = 0V	-	-5	-	dB	
RA.	RX Gain	High Gain Mode	11	12	-	uБ	
NF	Noise Figure	High Gain Mode	-	2.5	-	dB	
	Input Return Loss	At the Antenna port	-	12	-		
RXrl	Output Return Loss	At RX RF output	-	8	-	dB	
RxIP1DB	Input P1DB	Measured at ANT Port; High Gain Mode	-	-5	-	dBm	
		LNA Bypass Mode	-	10	-		
Rx_2.4int	Max 2.4Ghz interferer 1 dB degradation of IP1DB Amplitude		-	-10	-7	dBm	
T _{on/off}	T/R on/off switching speed	C0, C1 (50%) to RF output (10% or 90%)	-	300	-	nSec	



Power Detector Characteristics

Conditions: Vcc = VEN =C0= VDD = 3.3V, C1 = 0V, f = 5.4 GHz, TA = 25 °C, as measured on Skyworks Solutions' SE5007BT-EV1 evaluation board, unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
PDR	Pout detect range	-	0	-	P _{1dB}	dBm
VDET ₂₂	Detector voltage	Роит = 22 dBm	0.7	-	0.9	V
VDET ₁₆	Detector voltage	Роит = 16 dBm	0.50	-	0.60	V
VDET ₂	Detector voltage	Pout = 2 dBm	0.25	-	0.35	V
PDZout	Output Impedance	-	-	5	-	KΩ

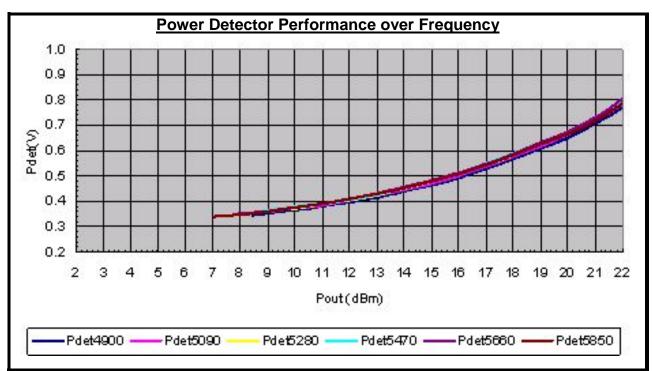


Figure 3: SE5007BT Power Detector Characteristic



Package Diagram

This package is Pb free and RoHS compliant. The product is rated MSL1.

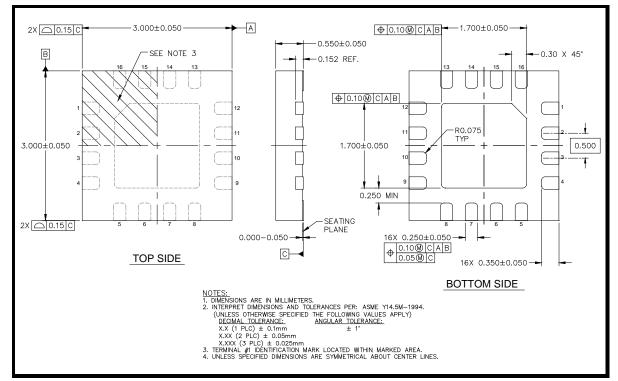


Figure 4: SE5007BT Package Diagram



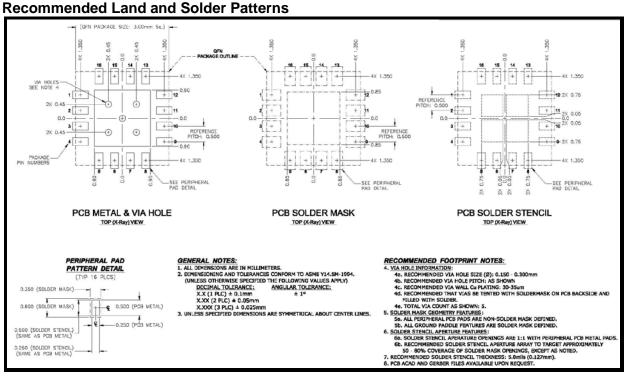
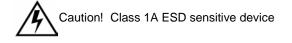


Figure 5: SE5007BT Recommended Land and Solder Pattern

Package Handling Information

Because of its sensitivity to moisture absorption, instructions on the shipping container label must be followed regarding exposure to moisture after the container seal is broken, otherwise, problems related to moisture absorption may occur when the part is subjected to high temperature during solder assembly. The SE5007BT is capable of withstanding a Pb free solder reflow. Care must be taken when attaching this product, whether it is done manually or in a production solder reflow environment. If the part is manually attached, precaution should be taken to insure that the device is not subjected to temperatures above its rated peak temperature for an extended period of time. For details on both attachment techniques, precautions, and handling procedures recommended, please refer to:

- "Quad Flat No-Lead Module Solder Reflow & Rework Information", Document Number QAD-00045
- "Handling, Packing, Shipping and Use of Moisture Sensitive QFN", Document Number QAD-00044





Branding Information

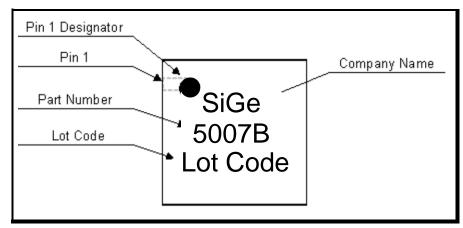


Figure 6: SE5007BT Branding

Tape and Reel Information

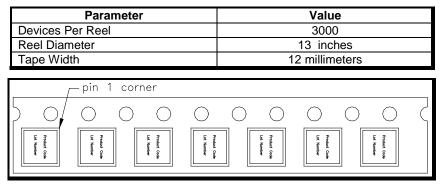


Figure 7: SE5007BT-R Tape and Reel Information

Document Change History

Revision	Date	Notes
1.0	Nov 03, 2010	Created
1.1	Nov 22, 2010	Updated Supply voltage specs
1.2	Dec 20, 2010	Corrected RX Conditions in Control Logic table
1.3	Jan 03, 2011	Updated recommended storage temperature
1.4	Feb 8, 2011	Added 4V operation, Mask Performance, Added reference to blocked RF ports on the block diagram
1.5	Apr 25, 2011	Update VENH (min) from 2.8V to 1.6V Corrected product description – removed reference to Balun
1.6	Apr 11, 2012	Updated with Skyworks logo and disclaimer statement